



### DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

### **Product Summary**

| V <sub>(BR)DSS</sub> | R <sub>DS(ON)</sub> Max      | I <sub>D</sub> Max<br>T <sub>A</sub> = +25°C |
|----------------------|------------------------------|--|
| 50V                  | 3.5Ω @ V <sub>GS</sub> = 10V | 200mA  |

### Description

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

Load Switch

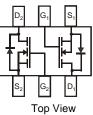
### **Features**

- Low On-Resistance .
- Low Gate Threshold Voltage .
- Low Input Capacitance •
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BSS138DWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 gualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)



Internal Schematic

### Ordering Information (Note 4)

|              | Part Number  | Case   | Packaging          |  |  |  |
|--------------|--|--------|--------------------|--|--|--|
|              | BSS138DWQ-7  | SOT363 | 3,000/Tape & Reel  |  |  |  |
| BSS138DWQ-13 |  | SOT363 | 10,000/Tape & Reel |  |  |  |
| Notes:       | votes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. |        |                    |  |  |  |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free. "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

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| l | N/         | ۲ |   | 8 | 36> | 1 |
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K38 = Product Type Marking Code YM = Date Code Marking Y or = Year (ex: D = 2016) M = Month (ex: 9 = September)

| Date Code Key | 1 |
|---------------|---|
|---------------|---|

| Date Code Rey |      |      |     |      |       |      |     |      |      |      |      |      |
|---------------|------|------|-----|------|-------|------|-----|------|------|------|------|------|
| Year          | 2005 | 2006 |     | 2016 | 5 201 | 7 20 | 18  | 2019 | 2020 | 2021 | 2022 | 2023 |
| Code          | S    | Т    |     | D    | E     |      | F   | G    | Н    |      | J    | K    |
| Month         | Jan  | Feb  | Mar | Apr  | Мау   | Jun  | Jul | Aug  | Sep  | Oct  | Nov  | Dec  |
| Code          | 1    | 2    | З   | 4    | 5     | 6    | 7   | 8    | Q    | 0    | N    | П    |

### SOT363



Top View



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic              |            | Symbol           | BSS138DW | Units |
|-----------------------------|------------|------------------|----------|-------|
| Drain-Source Voltage        |            | V <sub>DSS</sub> | 50       | V     |
| Drain-Gate Voltage (Note 7) |            | V <sub>DGR</sub> | 50       | V     |
| Gate-Source Voltage         | Continuous | V <sub>GSS</sub> | ±20      | V     |
| Drain Current (Note 5)      | Continuous | ID               | 200      | mA    |

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                          | Symbol               | BSS138DW    | Units |
|---|----------------------|-------------|-------|
| Total Power Dissipation (Note 5)        | PD                   | 200         | mW    |
| Thermal Resistance, Junction to Ambient | R <sub>0JA</sub>     | 625         | °C/W  |
| Operating and Storage Temperature Range | TJ, T <sub>STG</sub> | -55 to +150 | °C    |

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                    | Symbol              | Min | αvΤ | Max  | Unit | Test Condition  |
|-----------------------------------|---------------------|-----|-----|------|------|---|
| OFF CHARACTERISTICS (Note 6)      |                     |     |     |      |      |   |
| Drain-Source Breakdown Voltage    | BV <sub>DSS</sub>   | 50  | 75  | _    | V    | $V_{GS} = 0V, I_D = 250 \mu A$                          |
| Zero Gate Voltage Drain Current   | IDSS                | _   |     | 0.5  | μA   | $V_{DS} = 50V, V_{GS} = 0V$                             |
| Gate-Body Leakage                 | I <sub>GSS</sub>    | _   |     | ±100 | nA   | $V_{GS} = \pm 20V, V_{DS} = 0V$                         |
| ON CHARACTERISTICS (Note 6)       |                     |     |     |      |      | ·   |
| Gate Threshold Voltage            | V <sub>GS(TH)</sub> | 0.5 | 1.2 | 1.5  | V    | $V_{DS} = V_{GS}$ , $I_D = 250 \mu A$                   |
| Static Drain-Source On-Resistance | R <sub>DS(ON)</sub> | _   | 1.4 | 3.5  | Ω    | $V_{GS} = 10V, I_D = 0.22A$                             |
| Forward Transconductance          | <b>g</b> fs         | 100 |     | _    | mS   | V <sub>DS</sub> =25V, I <sub>D</sub> = 0.2A, f = 1.0KHz |
| DYNAMIC CHARACTERISTICS           |                     |     |     |      |      | •   |
| Input Capacitance                 | C <sub>ISS</sub>    | _   |     | 50   | pF   |   |
| Output Capacitance                | Coss                | _   | _   | 25   | pF   | $V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$                 |
| Reverse Transfer Capacitance      | C <sub>RSS</sub>    |     |     | 8.0  | pF   |   |
| SWITCHING CHARACTERISTICS         |                     |     |     | •    |      | •   |
| Turn-On Delay Time                | t <sub>D(ON)</sub>  |     |     | 20   | ns   | $V_{DD} = 30V, I_D = 0.2A,$                             |
| Turn-Off Delay Time               | t <sub>D(OFF)</sub> |     |     | 20   | ns   | $R_{GEN} = 50\Omega$                                    |

Notes:

5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown at http://www.diodes.com/package-outlines.html.

6. Short duration pulse test used to minimize self-heating effect.

7.  $R_{GS} \le 20K\Omega$ .





-55℃

25°C

150℃

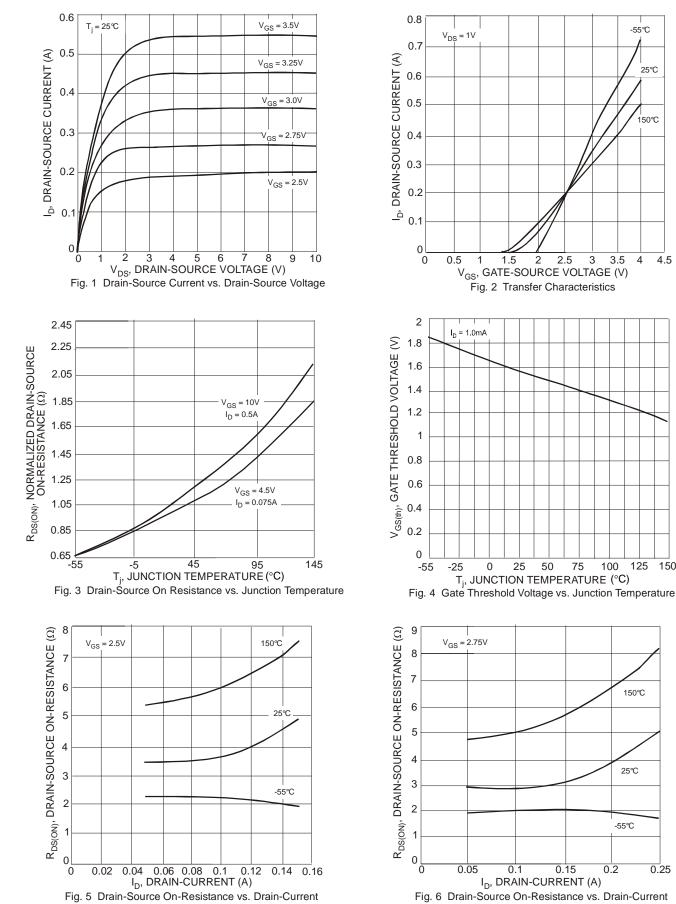
4 4.5

125

150℃

25℃

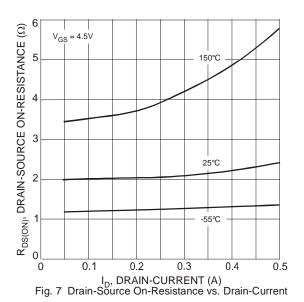
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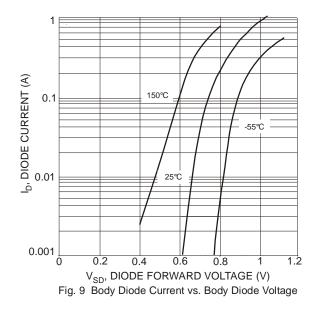


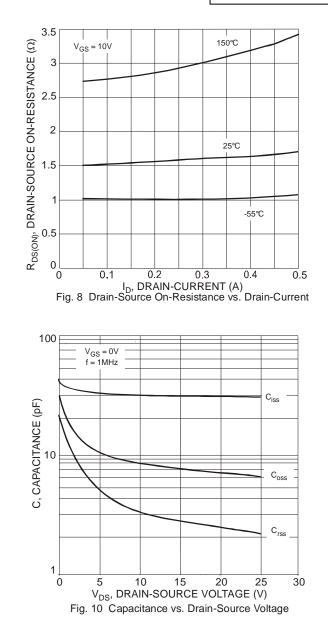
0.25



# BSS138DWQ



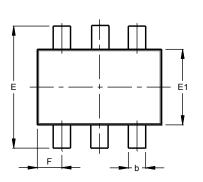


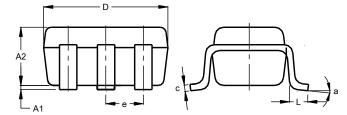




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





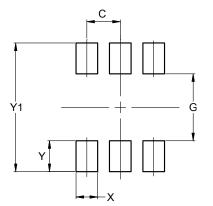
| SOT363 |       |         |       |  |  |  |  |
|--------|-------|---------|-------|--|--|--|--|
| Dim    | Min   | Max     | Тур   |  |  |  |  |
| A1     | 0.00  | 0.10    | 0.05  |  |  |  |  |
| A2     | 0.90  | 1.00    | 1.00  |  |  |  |  |
| b      | 0.10  | 0.30    | 0.25  |  |  |  |  |
| c      | 0.10  | 0.22    | 0.11  |  |  |  |  |
| D      | 1.80  | 2.20    | 2.15  |  |  |  |  |
| Е      | 2.00  | 2.20    | 2.10  |  |  |  |  |
| E1     | 1.15  | 1.35    | 1.30  |  |  |  |  |
| е      | C     | ).650 B | SC    |  |  |  |  |
| F      | 0.40  | 0.45    | 0.425 |  |  |  |  |
| L      | 0.25  | 0.40    | 0.30  |  |  |  |  |
| а      | 0°    | 8°      | _     |  |  |  |  |
| All    | Dimen | sions   | in mm |  |  |  |  |

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363

SOT363



| Dimensions | Value<br>(in mm) |
|------------|------------------|
| С          | 0.650            |
| G          | 1.300            |
| Х          | 0.420            |
| Y          | 0.600            |
| ¥1         | 2.500            |



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